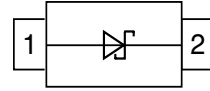
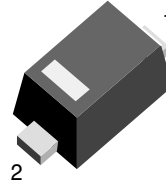


Small Signal Schottky Diode

Features

- These diodes feature very low turn-on voltage and fast switching.
- These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges.
- Space saving SOD-523 package
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



19020

Mechanical Data

Case: SOD-523 Plastic case

Molding Compound Flammability Rating:

UL 94 V-0

Terminals: High temperature soldering guaranteed:

260 °C/10 sec. at terminals

Weight: approx. 1.6 mg

Packaging Codes/Options:

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box

GS08 / 3 k per 7" reel (8 mm tape), 15 k/box

Parts Table

Part	Ordering code	Marking	Remarks
BAS520-02V	BAS520-02V-GS18 or BAS520-02V-GS08	T	Tape and Reel

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Repetitive peak reverse voltage		V _{RRM}	30	V
Forward continuous current	T _{amb} = 25 °C	I _F	200	mA
Power dissipation	T _{amb} = 25 °C	P _{tot}	200	mW

Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Junction soldering point		R _{thJS}	100	K/W
Junction temperature		T _j	125	°C
Storage temperature range		T _S	- 55 to +125	°C

Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Reverse breakdown voltage	I _R = 1 μA (pulsed)	V _(BR)	30			V
Leakage current	Pulse test V _R = 30 V, t _p < 300 μs	I _R		0.5	1	μA
Forward voltage	Pulse test t _p < 300 μs, I _F = 1.0 mA	V _F			320	mV
	Pulse test t _p < 300 μs, I _F = 200 mA,	V _F			600	mV
Diode capacitance	V _R = 0 V, f = 1 MHz	C _{tot}		25	30	pF
Reverse recovery time	I _F = 10 mA, I _R = 10 mA, I _{rr} = 1 mA, R _L = 100 Ω	t _{rr}		10		ns

Typical Characteristics (T_{amb} = 25 °C unless otherwise specified)

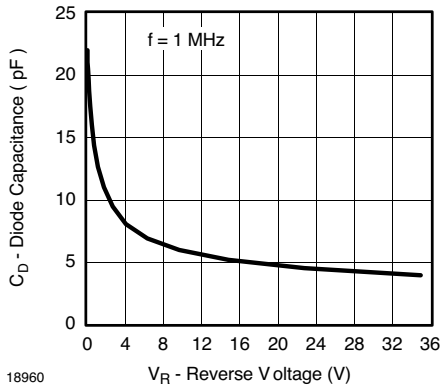


Figure 1. Typical Capacitance vs. Reverse Voltage

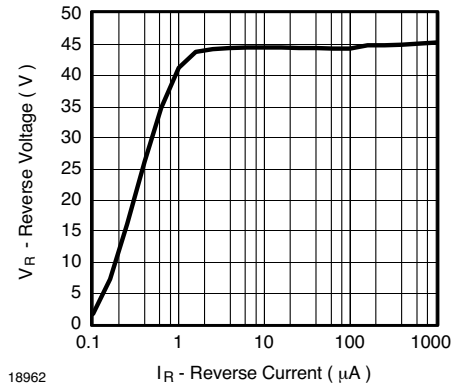


Figure 3. Typical Reverse Voltage vs. Reverse Current

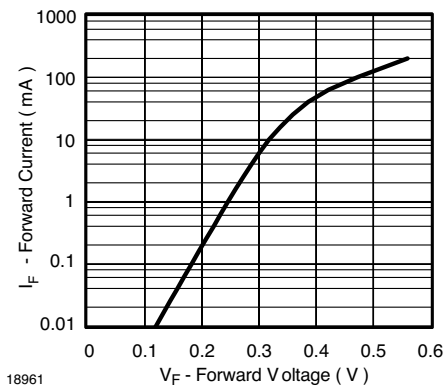
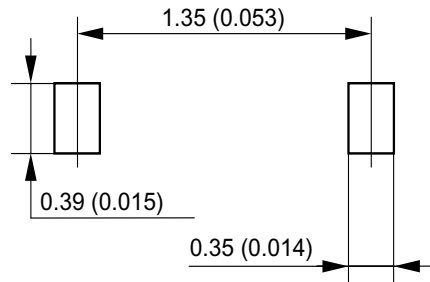
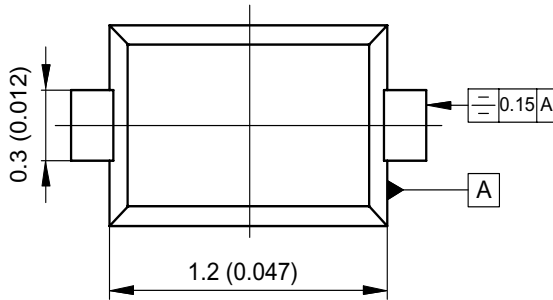
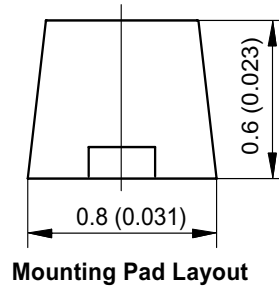
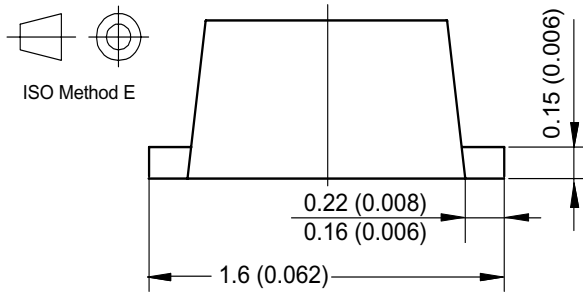
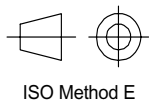


Figure 2. Forward Current vs. Forward Voltage

Package Dimensions in mm (Inches)



16864

Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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